NSN 5961-01-410-7810

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-410-7810 **Inclosure Material:** Ceramic **Overall Length:** 0.176 inches **Function For Which Designed:** Voltage variable capacitor **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 working peak reverse voltage, peak total value **Capacitance Rating In Picofarads:** 10.0 **Test Data Document:** 60994-104460 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: